



■ Features

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■ Description

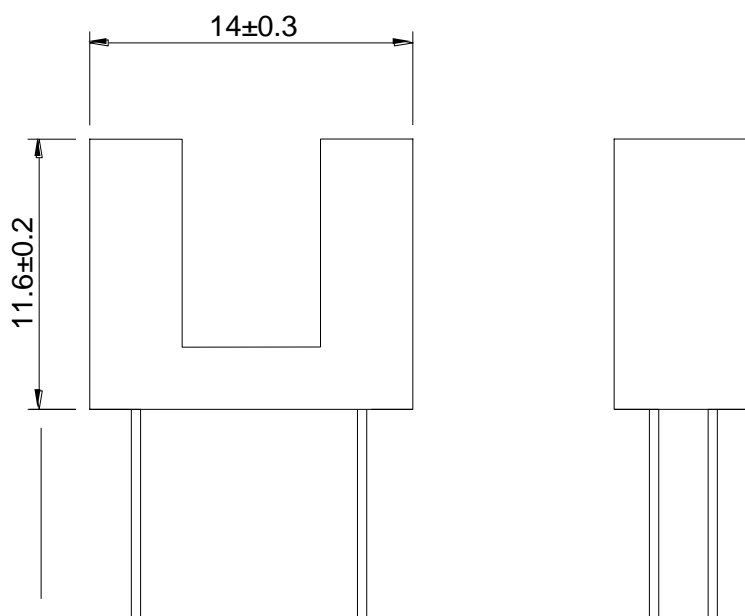
- The ITR2C-554624-2.8 consist of an infrared emitting diode and an silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing,
- The phototransistor receives radiation from the IR LED only .This is the normal situation.
- But when an object is in between , phototransistor could not receives the radiation.

■ Applications

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■ Device Selection Guide

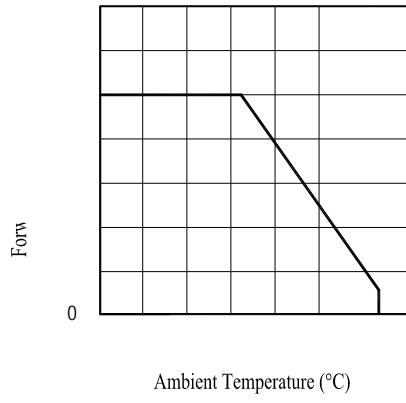
Device No.	Chip Material	LENS COLOR

■ Package Dimensions**Notes:**

1. All dimensions are in millimeters.
2. Tolerance is ± 0.20 mm unless otherwise noted.
3. Lead spacing is measured where the leads emerge from the package.

■ Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol Ratings	Unit	
Power Dissipation at(or below) 25°C Free Air Temperature			



LIGHT

LIGHT ELECTRONICS CO., LTD.

■ Tube Packing

